

J230, J231

N-Channel Silicon Junction Field-Effect Transistor

• Audio Amplifiers

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

Reverse Gate Source & Reverse Gate Drain Voltage	- 40 V
Continuous Forward Gate Current	50 mA
Continuous Device Power Dissipation	360 mW
Power Derating	3.27 mW/°C

At 25°C free air temperature:

Static Electrical Characteristics

		J230			J231			Process NJ16	
		Min	Typ	Max	Min	Typ	Max	Unit	Test Conditions
Gate Source Breakdown Voltage	$V_{(BR)GSS}$	- 40			- 40			V	$I_G = -1\mu\text{A}, V_{DS} = 0\text{V}$
Gate Reverse Current	I_{GSS}			- 250			- 250	pA	$V_{GS} = -30\text{V}, V_{DS} = 0\text{V}$
Gate Operating Current	I_G		- 2			- 2		pA	$V_{DS} = 20\text{V}, I_D = 0\text{V}$
Gate Source Cutoff Voltage	$V_{GS(OFF)}$	- 0.5		- 3	- 1.5		- 5	V	$V_{DS} = 20\text{V}, I_D = 1\mu\text{A}$
Drain Saturation Current (Pulsed)	I_{DSS}	0.7		3	2		6	mA	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$

Dynamic Electrical Characteristics

Common Source Forward Transconductance	g_{fs}	1000		3500	1500		4000	μS	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ kHz}$
Common Source Output Conductance	g_{os}		1.5			3		μS	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ kHz}$
Common Source Input Capacitance	C_{iss}		4			4		pF	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ MHz}$
Common Source Reverse Transfer Capacitance	C_{rss}		1			1		pF	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ MHz}$
Equivalent Short Circuit Input Noise Voltage	\hat{e}_N		8	30		8	30	nV/√Hz	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}$	$f = 10\text{ Hz}$
			2			2		nV/√Hz	$V_{DS} = 10\text{V}, V_{GS} = 0\text{V}$	$f = 1\text{ kHz}$

TO-226AA Package

Dimensions in Inches (mm)

Pin Configuration

1 Drain, 2 Source, 3 Gate

Surface Mount

SMPJ230, SMPJ231



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